

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1259374	test	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 14:54
L2	179481	piezoelectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 14:56
L3	2	"20040207033"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 17:57
L4	15	FB near DRAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 17:58
L5	9	FBD RAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:02
L6	7958	floating near body	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:10
L7	11	6 with RAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:03
L8	10	("20020051378" "20020130341" "5448513" "5798965" "6130450" "6238967" "6538916" "6560142" "6620679" "6632723").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/06 18:10
L9	1	"20020130341".PN.	US-PGPUB	OR	OFF	2005/08/06 18:05
L10	1	"20020051378".PN.	US-PGPUB	OR	OFF	2005/08/06 18:07
L11	53762	second near transistor	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/06 18:10

L12	22913	floating with body	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:10
L13	404	11 and 12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:11
L14	133	13 and DRAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:11
L15	15	14 and capacitorless	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:31
L16	1066	halo adj implant\$7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:32
L17	0	15 and 16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:33
L18	2	16 and FBDRAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:50
L19	216	16 and DRAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:51
L20	220	16 and \$2DRAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 18:51
L21	12	20 and (float\$5 with body)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 19:07

L22	0	asymetric with doping with transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 19:08
L23	1	asymetric with doping	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 19:08
L24	2	asymetric same doping	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 19:09
L25	0	asymetric near memory near cell	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/06 19:09
L26	191	asymmetric with doping	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 19:10
L27	0	asymmetric with doping with memery	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 19:10
L28	60	26 same transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 19:17
L29	1	asymmetric near doping near transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 19:19
L30	992	asymmetric with transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 19:19
L31	123	30 and SOI	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 20:52

L32	12	asymmetric with source near drain near doping	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 21:35
L33	3	"6861689"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 21:53
L34	826	257/202.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 21:53
L35	0	30 and 34	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 21:54
L36	10	34 and asymmetric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 21:56
L37	267	257/E21.618.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 21:57
L38	15	37 and asymmetric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/06 21:57